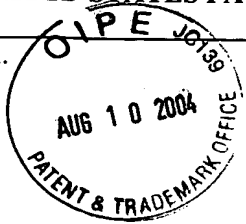


IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): FUKUDA et al.	Atty. Dkt.: 01-103-CON8
Serial No.: 10/699,746	Group Art Unit: 2811
Filed: November 4, 2003	Examiner: Unknown
Title: SEMICONDUCTOR DEVICE HAVING RADIATION STRUCTURE	



Commissioner for Patents
Arlington, VA 22202

Date: August 10, 2004

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §1.56, the references listed on the attached Form PTO-1449 are being brought to the attention of the Examiner without any admission that they constitute statutory prior art, or without any admission that they contain subject matter that anticipates the invention or renders the invention obvious to a person of ordinary skill in the art.

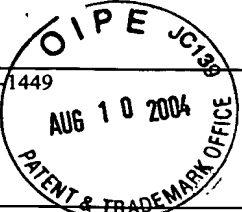
Further, pursuant to 37 C.F.R. §1.97(e), the undersigned hereby certifies that each listed reference was cited in a Communication (copy enclosed) from a foreign patent office in connection with a counterpart foreign application not more than three months prior to the filing of this statement.

Although no fees are believed to be due at this time, it is respectfully requested that any such fees be charged to Deposit Account 50-1147. Also, the Examiner is requested to initial the attached PTO Form-1449 and to return a copy of same to the undersigned attorney as proof that the listed references have been considered and made of record.

Respectfully submitted,

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FORM PTO-1449			PATENT APPLICATION	
			Page 1 of 1	
			ATTY. DKT NO. 01-103-CON8	SER. NO. 10/699,746
			APPLICANT FUKUDA et al.	
FILING DATE November 4, 2003		GROUP 2811		

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS

FOREIGN PATENT DOCUMENTS

								TRANSLATION	
		DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO
		JP-A-10-125700	05/15/98	JAPAN				Engl. Abstract	
		JP-A-61-147539	07/05/86	JAPAN				Engl. Abstract	

* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at <http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX>.

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER		DATE CONSIDERED